

2.4GHz TO 2.5GHz SINGLE-BAND

FRONT END MODULE



Package Style: QFN, 16-pin, 3mmx3mmx0.5mm

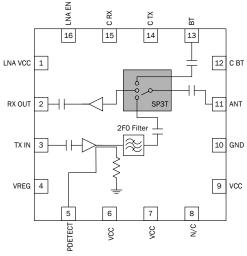


Features

- Single Module Radio Front End
- Single Supply Voltage 3.0V to 5V
- Integrated 2.4GHz to 2.5GHz b/g Amplifier LNA, TX/RX Switch, P_{DETECT} Coupler
- P_{OUT} = 17 dBm, 11g, OFDM at <3% EVM, 21dBm 11b Meeting 11b Spectral Mask
- Low Height Package, Suited for SiP and CoB Designs

Applications

- Cellular handsets
- Mobile devices
- Tablets
- Consumer electronics
- Gaming
- Netbooks/Notebooks
- TV/monitors/video
- SmartEnergy



Functional Block Diagram

Product Description

The RF5725 is a single-chip integrated front-end module (FEM) for high performance WiFi applications in the 2.4GHz to 2.5GHz ISM band. This FEM greatly reduces the number of external components, minimizing footprint and assembly cost of the overall 802.11b/g solution. The RF5725 has an integrated b/g power amplifier, LNA, a Coupler Power detector, and TX filtering. It also is capable of switching between WiFi RX, WiFi TX, and BTH RX/TX operations. This device is manufactured using GaAs HBT and pHEMT processes on a 3mmx3mmx0.5mm 16-pin QFN package. This module meets or exceeds the RF front-end needs of 802.11b/g WiFi RF systems.

Ordering Information

RF5725 Standard 25 piece bag RF5725SR Standard 100 piece reel RF5725TR7 Standard 2500 piece reel

RF5725PCK-410 Fully assembled evaluation board tuned for 2.4 GHz to

2.5 GHz and 5 loose sample pieces

Optimum Technology Matching® Applied

	•	O, O	
☐ GaAs HBT	☐ SiGe BiCMOS	☑ GaAs pHEMT	☐ GaN HEMT
☐,GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	
✓ InGaP HBT	☐ SiGe HBT	☐ Si BJT	
✓ InGaP HBT	□ SiGe HBT	∐ Si BJT	

RF5725



Absolute Maximum Ratings

Parameter	Rating	Unit
DC Supply Voltage	5.0	V
DC Supply Current	240	mA
Full Specification Temp Range (Full Spec. Compliant)	-10 to +70	°C
Extreme Operating (Reduced Performance)	-40 to -10 +70 to +85	
Storage Temperature	-40 to +150	°C
Maximum TX Input Power for 11b/g (No Damage)	5	dBm
Moisture Sensitivity	MSL2	



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition	
Parameter	Min. Typ.		Max.	Unit	Condition	
2.4 GHz Transmit Parameters	_					
Compliance					IEEE802.11b, IEEE802.11g, FCC CFG 15.247, .205, .209	
Nominal Conditions					Specifications must be met across $V_{\rm CC}$, $V_{\rm REG}$, frequency, process, and temperature, unless otherwise specified.	
Frequency	2.4		2.5	GHz		
Output Power						
11g	16	17		dBm	OFDM 54Mbps, V _{CC} =3.3 ≤ 4.2V, T=10° to 75°C	
11g	15			dBm	Derated performance over Freq, Temp, and Process.	
11b	20	21		dBm	11Mbps, CCK, VCC= $3.3 \le 4.2 \text{ V}$, T= $10 ^{\circ}\text{C}$ to + $75 ^{\circ}\text{C}$.	
11b	18	19		dBm	Derated performance over Freq, Temp, and Process.	
EVM*		3.0	4.0	%	54Mbps OFDM $V_{CC} \ge 3.6V$, 50Ω , see Note 1, 5.	
Adjacent Channel Power						
ACP1		-38	-34	dBc	P _{OUT(b)} =21dBm, 1Mbps CCK, Note 4. Meeting 11b spectral mask requirements with ≥ 3dB margin	
ACP2		-56	-53	dBc	P _{OUT(b)} =21dBm, 1Mbps CCK, Note 4. Meeting 11b spectral mask requirements with ≥ 3dB margin	
Gain	24	26		dB		
Gain Variation						
V _{CC}			0.7	dB/V		
Frequency	-0.5		+0.5	dB	2.4GHz to 2.5GHz	
Power Detect						
Voltage Detect	0.1		1.5	V		
P _{OUT} =17dBm		1.0		V	IEEE802.11g, 54Mbps 64QAM modulation	
Input Resistance		10		kΩ		
Input Capacitance			5	pF		
Bandwidth	800	1000		kHz		
P _{DETECT} Accuracy	-1.5		+1.5	dB	P _{OUT} =17dBm	

^{*}The EVM specification is obtained with a signal generator that has an EVM level <0.7%.



Downston	Specification			Hoit	O	
Parameter	Min. Typ. Max.		Unit	Condition		
2.4 GHz Transmit Parameters,	_	<i></i>				
cont'd						
Sensitivity						
>10dBm	25			mV/dB		
0 <p<sub>OUT<10dBm</p<sub>	8			mV/dB		
Current Consumption						
I _{cc}		130		mA	RFP _{OUT} =17dBm, 54Mbps IEEE802.11g	
33		190			RFP _{OUT} =21dBm, 11Mbps IEEE802.11b	
Idle		95		mA	V _{CC} =3.6V, V _{REG} =2.85V, and RF=0FF	
		3	5	mA	THE STORY TREES ELECTRICATE OF THE STORY OF	
I _{REG}		2	10			
Leakage Leakage	3.0	3.6	4.5	μA V		
Power Supply	2.75	2.85	2.95	V		
V _{REG}	2.75		2.95			
Input/Output Impedance		50		Ω	No deverge	
Ruggedness Output VSWR	10:1				No damage	
·	10:1				Maximum: operating voltage, input power, temperature	
Stability Output VSWR	5:1				All phage angles, no anurious or assillations	
·	2:1				All phase angles, no spurious or oscillations.	
Out of Band Performance S21 (DC to 960 MHz)			0	dB		
S21 (DC to 960MHz)			18	dB		
S21 (1805MHz to 1990MHz)			20	dВ		
S21 (2110 MHz to 2170 MHz)			25	dВ	All other ports terminated in their nominal impedances	
Thermal Resistance		79.3	25	°C/W	V _{CC} =3.3, V _{REG} =2.9V, C_TX=3.3, C_RX=C_BT=GND,	
memai nesistance		19.5		C/ VV	P _{OUT} =17dBm, Modulation=On, Freq=2.45GHz,	
					D _{CC} =100%, T=85°C	
		87.2		°C/W	V _{CC} =4.8, V _{REG} =3V, C_TX=3.3, C_RX=C_BT=GND,	
				,	P _{OUT} =17dBm, Modulation=On, Freq=2.45GHz,	
					D _C =100%, T=85°C	
Harmonics					RBW=1MHz. Measured at 1Mbps.	
Second		-35	-32	dBm	4.80 GHz to 5.00 GHz	
Third		-45	-42	dBm	7.20GHz to 7.50GHz	
Turn-On/Off Time		0.5	1.0	μS	Output stable to within 90% of final gain	
Antenna Port Impedance					Antenna port is a DC short to ground	
Input		50		Ω	Receive	
Output		50		Ω	Transmit	
Switch Control Voltage						
Low		0	0.2	V		
High	2.7	2.8	3.6	V		
Switch Control Current			10	μΑ	Per control line	
Switch Control Speed			100	nsec		
ESD					All pins unless otherwise stated.	
Human Body Model	1000			V	EIA/JESD22-114A	
Charge Device Model	500			V	EIA/JESD22-C101C	



Parameter	Specification		Unit	Condition	
Farantelei	Min.	Тур.	Max.	Ullit	Condition
2.4 GHz Receive Parameters					
Frequency	2.4		2.5	GHz	
Receive Gain	10	13	16	dB	WiFi RX mode only
	7	10	13	dB	WiFi RX and BT RX mode
Noise Figure		2.1		dB	WiFi RX mode only
		5.5		dB	WiFi RX and BT RX mode
Passband Ripple	-1		+1	dB	
Output Return Loss			-9.6	dB	
Output Impedance		50		Ω	No external matching
Current Consumption			30	μΑ	
LNA VCC		8		mA	LNA ON
LNA enable		2		mA	
		5		uA	LNA OFF
<i>Bluetooth</i> ™ Parameters					
Frequency	2.4		2.5	GHz	
Insertion Loss		0.8	1.2	dB	SP3T switch, all unused ports terminated into their nom-
					inal impedance. Bluetooth TM mode only
		3.75	5.50	dB	WiFi RX and BT RX mode
Passband Ripple	-0.2		+0.2	dB	
Input/Output Power			8	dBm	
Output Return Loss			-10	dB	
Output Impedance		50		Ω	No external matching
Current Consumption			30	μΑ	Switch leakage current

^{*}The EVM specification is obtained with a signal generator that has an EVM level <0.7%.

- Note 1. The PA module must operate with gated bias voltage input at 1% to 99% duty cycle.
- Note 2. No external matching components. Antenna port is a DC short to GND.
- Note 3. Values to be agreed upon characterization data review: current, gain, return loss, detector sensitivity, and output power.
- Note 4. The output power for channels 1 and 13 may be reduced to meet FCC restricted band requirements.
- Note 5: EVM at lower output power values will never exceed nominal operating power EVM. EVM should be monotonic from OdBm to rated output power.

Isolation Table

Parameter	Min.	Тур.	Max.	Unit
WiFi RX to BT RX/TX	20			dB
WiFi TX to BT RX/TX	20			dB
WiFi RX to WiFi TX	20			dB
WiFi RX and BT RX Mode	9			dB

Switch Control Logic

Mode	C_RX	C_TX	C_BT
Bluetooth TM	L	L	Н
WiFi Tx	L	Н	L
WiFi Rx	Н	L	L
WiFi Rx/BT	Н	L	Н

^{*}The FEM can simultaneously receive WiFi and $Bluetooth^{TM}$ in the WiFi RX and BT RX Mode.



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Pin	Function	Description
1	LNA VCC	Voltage supply for the LNA (labeled VCC3 on evaluation board).
2	RX OUT	Receive port for 802.11b/g band. Internally matched to 50Ω . DC block provided.
3	TX	RF input for the 802.11b/g PA. Input is matched to 50Ω and DC block is provided.
4	VREG	Regulated voltage for the bias control circuit. An external bypass capacitor may be needed on the V _{REG} line for decoupling purposes.
5	PDETECT	Power detector voltage for TX section. PDET voltage varies with output power. May need external decoupling capacitor for module stability. May need external circuitry to bring output voltage to desired level.
6	VCC	Supply voltage for the bias circuit of the PA.
7	VCC	Supply voltage for the first stage of the PA. Add an external 0.1 uF capacitor for low frequency decoupling.
8	N/C	No connect.
9	VCC	Supply voltage for the second stage of the PA. Add an external 0.1 uF capacitor for low frequency decoupling.
10	GND	Ground.
11	ANT	Port matched to 50Ω and is a DC short to ground.
12	C_BT	Switch control port. See truth table for proper level.
13	BT	RF bidirectional port for Bluetooth $^{\text{TM}}$. Input is matched to 50Ω and DC block is provided.
14	C_TX	Switch control port. See switch truth table for proper level.
15	C_RX	Switch control port. See switch truth table for proper level.
16	LNA_EN	LNA enable pin. This is an active high control. A bypass capacitor may be needed for supply noise decoupling.

Package Drawing

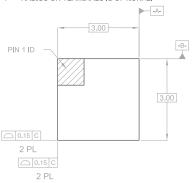
NOTES:

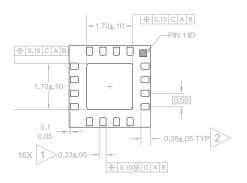
1 DIMENSION APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25mm AND 0.30mm FROM TERMINAL TIP.

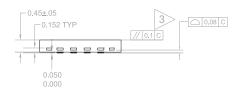
2 DIMENSION REPRESENTS TERMINAL PULL BACK FROM PACKAGE EDGE UP TO 0.1mm IS ACCEPTABLE.

3 COPLANARITY APPLIES TO THE EXPOSED HEAT SLUG AS WELL AS THE TERMINAL.

4 RADIUS ON TERMINALS IS OPTIONAL.

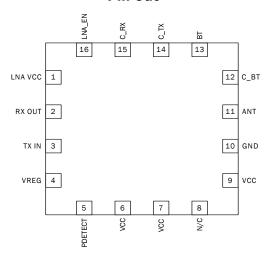






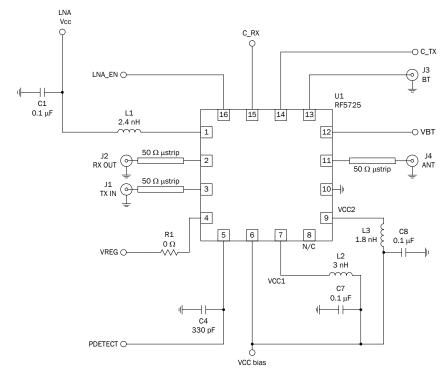


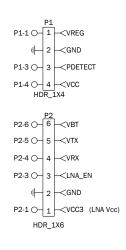
Pin Out





Evaluation Board Schematic





RF5725



Theory of Operation

The RF5725 FEM is a single-chip integrated front-end module (FEM) for high performance WiFi applications in the 2.4 GHz to 2.5 GHz ISM band. The FEM greatly reduces the number of external components minimizing footprint and assembly cost of the overall 802.11b/g solution. The RF5725 has an integrated b/g power amplifier, LNA, a Couple Power Detector, and TX filtering. It is also capable of switching between WiFi RX, WiFi TX, and BTH RX/TX operations. The device is manufactured using GaAs HBT and pHEMT processes on a 3mmx3mmx0.5mm 16-pin QFN package. The module meets or exceeds the RF front-end needs of the 802.11b/g WiFi RF systems.

The RF5725 is a very easy part to implement, but care in circuit layout and component selection is always advisable when designing circuits that operate at high frequencies. To reduce the design and optimization process on the customer application, the evaluation board layout should be copied as close as possible, in particular the ground and via configurations. Gerber files of RFMD PCBA designs can be provided upon request. The supply voltage lines should present an RF short to the FEM by using bypass capacitors on the VCC traces. Please contact RFMD Sales or Application Engineering for additional data and guidance.

To simplify bias conditions, the FR5725 requires a single positive supply voltage (VCC), a positive current control bias (VREG) supply, and a positive supply for switch control. The built in Coupler Power Detector of the FR5725 is very accurate and minimizes calibration time in the system. All inputs and outputs are internally matched to 50Ω .

Transmit Path

The RF5725 has a typical gain of 28dB form 2.4GHz to 2.5GHz, and delivers 17dBm typical output power under 54Mbps OFDM modulation and 21dBm under 1Mbps 11b modulation. The RF5725 requires a single positive of 3.3V to 4.2V to operate at full specifications. Current control optimization for the 802.11b/g band is provided through one bias control input pin (VREG). The VREG pin requires a regulated supply to maintain nominal bias current.

Out of Band Rejection

The RF5725 contains basic filtering components to produce a bandpass response for the transmit path. Due to space constraints inside the module filtering is limited to a few resonant poles. Depending upon the end-user's application, additional filters may be needed to meet the out of band rejection requirements of the system.

Receive Path

The 802.11b/g path has a 50Ω single-ended port with a nominal gain of 10dB in WiFi RX mode and 6dB in WiFi RX/BT mode. The Receive port return loss is 9.6dB minimum. The RF5725 is designed so that the SP3T may act as a 3dB splitter when placed in the WiFi RX and BT RX mode. In this mode, the FEM can receive $Bluetooth^{TM}$ and WiFi signals simultaneously with an additional 3dB of loss.



RF5275 Biasing Instructions:

- 802.11b/g Transmit:
 - Connect the FEM to a signal generator at the input and a spectrum analyzer at the output.
 - Bias V_{CC} to 3.6V first with V_{REG}=0.0V.
 - Refer to switch operational truth table to set the control lines at the proper levels for WiFi TX.
- Turn on V_{REG} to 2.85V (typ.). V_{REG} controls the current drawn bu the 802.11b/g power amplifier and the current should
 quickly rise to ~100 mA ± 20 mA for a typical part but it varies based on the output power desired. Be externally careful not
 to exceed 3.4V on the V_{REG} pin or the part may exceed device current limits.
- 802.11b/g Receive
 - To receive WiFi set the switch control lines per the truth table below.
- Bluetooth™ Receive
 - To receive *Bluetooth™* set the switch control lines per the truth table below.

Switch Control Logic

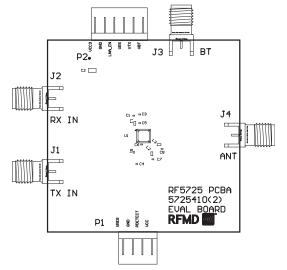
Mode	C_RX	C_TX	C_BT
Bluetooth TM	L	L	Н
WiFi Tx	L	Н	L
WiFi Rx	Н	L	L
WiFi Rx/BT	Н	L	Н

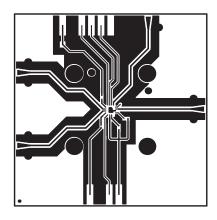
^{*}The FEM can simultaneously receive WiFi and BluetoothTM in the WiFi RX and BT RX Mode.

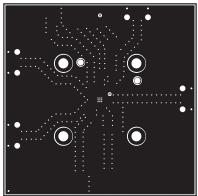


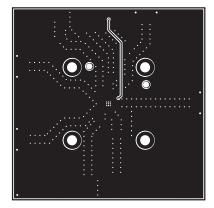
Evaluation Board Layout Board Size 2.0" x 2.0"

Board Thickness 0.032", Board Material FR-4, Multi-Layer











RF5725 Plots

